

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor dates sheds, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor dates sheds and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use on similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor and its officers, employees, subsidiaries, affliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any lay bed ON Semiconductor and its officers, employees, ween if such claim alleges that ON Semiconductor was negligent regarding the d



SEMICONDUCTOR®

AIRCHI

Data Sheet

May 2013

6A, 600V Hyperfast Diodes

The RHRD660S9A_F085 is hyperfast diodes with soft recovery characteristics ($t_{rr} < 30$ ns). It has half the recovery time of ultrafast diodes and are silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as freewheeling/ clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Formerly developmental type TA49057.



Features

- Hyperfast with Soft Recovery.....
- Reverse Voltage Up To600V
- Avalanche Energy Rated
- Planar Construction
- Qualified to AEC Q101
- RoHS Compliant

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

Ordering Information

PART NUMBER	PACKAGE	BRAND
RHRD660S9A_F085	TO-252	RHR660

Symbol



Packaging



Absolute Maximum Ratings $T_C = 25^{\circ}C$, Unless Otherwise Specified

	RHRD660S9A_F085	UNITS
Peak Repetitive Reverse Voltage	600	V
Working Peak Reverse Voltage	600	V
DC Blocking Voltage	600	V
Average Rectified Forward Current	6	A
Repetitive Peak Surge Current I _{FRM} (Square Wave, 20kHz)	12	A
Nonrepetitive Peak Surge Current I _{FSM} (Halfwave, 1 Phase, 60Hz)	60	A
Maximum Power Dissipation	50	W
Avalanche Energy (See Figures 10 and 11) E _{AVL}	10	mJ
Operating and Storage Temperature	-55 to 175	°C
Maximum Lead Temperature for Soldering		
(Leads at 0.063 in. (1.6mm) from case for 10s)	300	°C
Package Body for 10s, see Tech Brief 334T _{PKG}	260	°C

SYMBOL	TEST CONDITION	MIN	ТҮР	MAX	UNITS
V _F	I _F = 6A	-	-	2.1	V
	I _F = 6A, T _C = 150 ^o C	-	-	1.7	V
I _R	V _R = 600V	-	-	100	μΑ
	$V_{R} = 600V, T_{C} = 150^{\circ}C$	-	-	500	μΑ
t _{rr}	$I_F = 1A$, $dI_F/dt = 200A/\mu s$	-	-	30	ns
	$I_F = 6A$, $dI_F/dt = 200A/\mu s$	-	-	35	ns
t _a	$I_F = 6A$, $dI_F/dt = 200A/\mu s$	-	16	-	ns
t _b	$I_F = 6A$, $dI_F/dt = 200A/\mu s$	-	8.5	-	ns
Q _{RR}	$I_F = 6A$, $dI_F/dt = 200A/\mu s$	-	45	-	nC
CJ	V _R = 10V, I _F = 0A	-	20	-	pF
R _{θJC}		-	-	3	°C/W

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300µs, D = 2%).

 I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time (See Figure 9), summation of $t_a + t_b$.

 t_a = Time to reach peak reverse current (See Figure 9).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

Q_{RR} = Reverse recovery charge.

 C_{J} = Junction capacitance.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

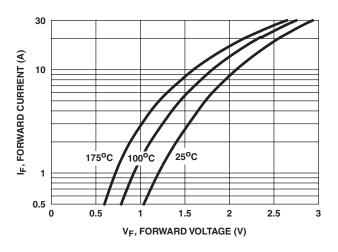


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

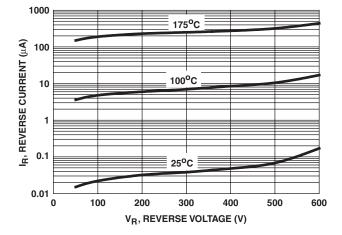


FIGURE 2. REVERSE CURRENT vs REVERSE

Typical Performance Curves (Continued)

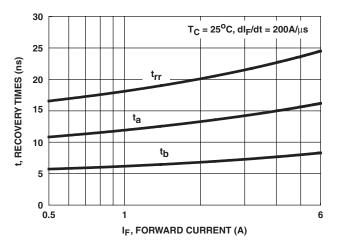
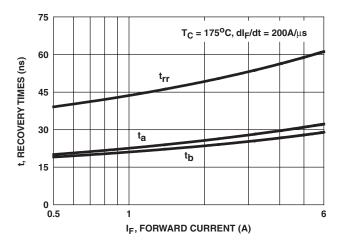


FIGURE 3. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT





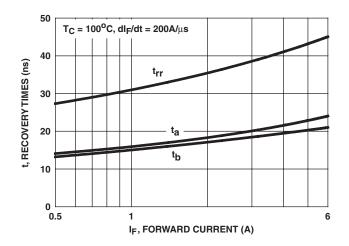


FIGURE 4. trr, ta AND tb CURVES vs FORWARD CURRENT

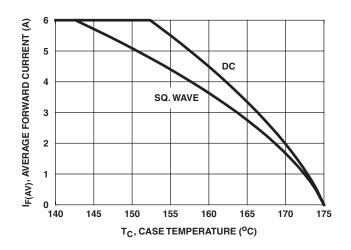


FIGURE 6. CURRENT DERATING CURVE

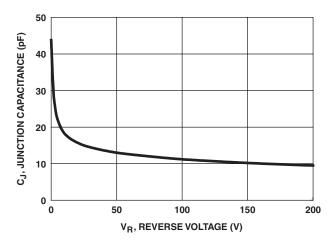
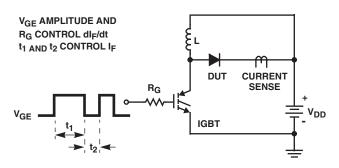


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuits and Waveforms





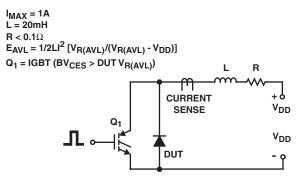


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

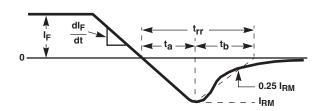


FIGURE 9. trr WAVEFORMS AND DEFINITIONS

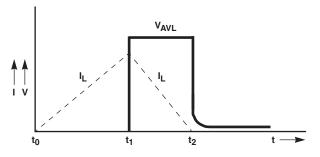


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS



TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower TM Auto-SPMT ^M AX-CAP ^{TM*} BitSiC [®] Build it Now TM CorePLUS TM CorePOWER TM CROSSVOLT TM CTL TM Current Transfer Logic TM DEUXPEED [®] Dual Cool TM EcoSPARK [®] EfficentMax TM ESBC TM EfficentMax TM ESBC TM Fairchild [®] Fairchild [®] Fairchild [®] Fairchild [®] Fairchild [®] Fact Quiet Series TM FACT [®] FastvCore TM FETBench TM FlashWriter [®] *	FPS™ F-PFS™ FRFET® Global Power Resource SM Green FPS™ Green FPS™ e-Series™ Gmax™ GTO™ IntelliMAX™ ISOPLANAR™ MegaBuck™ MiCROCOUPLER™ MicroPat™ MicroPak™ MicroPak™ MicroPak™ MillerDrive™ Motion-SPM™ Motion-SPM™ mWSaver™ OptiHiTT™ OPTOLOGIC® OPTOPLANAR®	Power-SPM [™] PowerXS [™] Programmable Active Droop [™] QFET [®] QS [™] Quiet Series [™] RapidConfigure [™] T ^M Saving our world, 1mW/W/kW at a time [™] SignalWise [™] SmartMax [™] SmartMax [™] SMART START [™] SMART START [™] SPM [®] STEALTH [™] SuperFET [®] SuperSOT [™] -6 SuperSOT [™] -6 SuperSOT [™] -6 SuperSOT [™] -8 SupreMOS [®] SyncFET [™] Sync-Lock [™] FGENERAL	The Power Franchise® The Right Technology for Your Success™ Pranchise TinyBoost™ TinyBoost™ TinyBuck™ TinyDogic® TINYOPTOT™ TinyPOwer™ TinyPOwer™ TinyPWM™ TinyWire™ TranSiC® TriFault Detect™ TRUECURRENT®* µSerDes™ Utra FRFET™ UniFET™ VCX™ VisualMax™ XS™
--	---	---	---

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Fairchild Semiconductor: RHRD660S9A_F085